

# Semiconductor Components, Instruments and Subsystems (SCIS)

Technology Community

Overview | 2023

SEMI speeds the time-to-better business results for its members across the global electronics design and manufacturing supply chain.



Г - COLLABORATE - INNOVATE - GROW - PROSPER



#### 50+ Years Later: SEMI is More Than Ever and Growing!



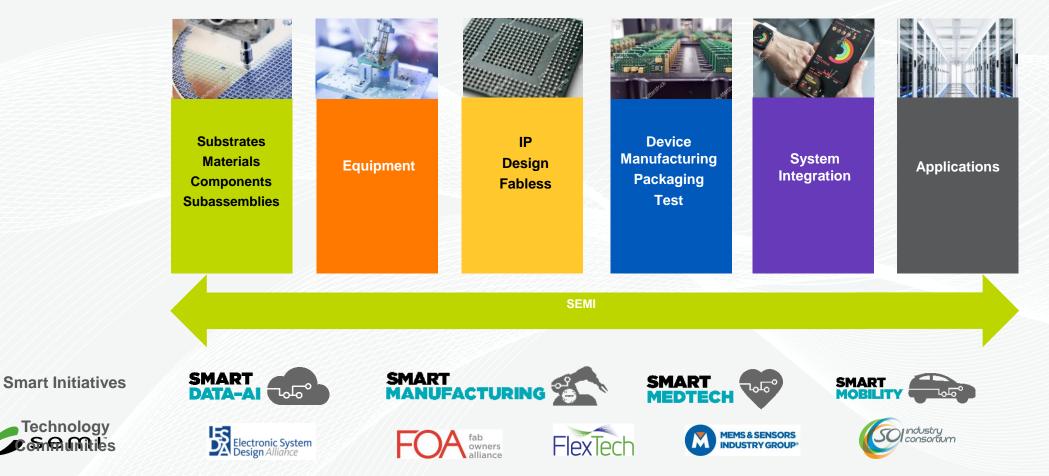
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CONNECT - COLLABORATE - INNOVATE - GROW - PROSPER



# SEMI Connects the Global Electronics Design and Manufacturing Supply Chain

Convergence and new disruptions are driving transformation to the digital era





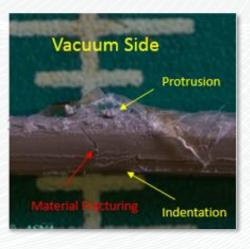
#### ONE MEMBERSHIP OPENS THE DOOR TO A WORLD OF TECHNOLOGY COMMUNITIES



# Supply Chain Issue

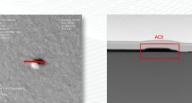
<u>Problem Statement</u>: Defects introduced by process-critical OEM components affect final wafer quality resulting in lower yields and higher manufacturing costs.

- Several yield excursions are linked to wide range of component and sub-components induced defectivity.
- Components and sub-components defect traceability lack the rigor for advanced technologies (detectability, sensitivity/methodology).
- Existing standards, if any, are inadequate for addressing advanced • process control requirements.





30-35 nm particles





# SEMI SCIS Technology Community

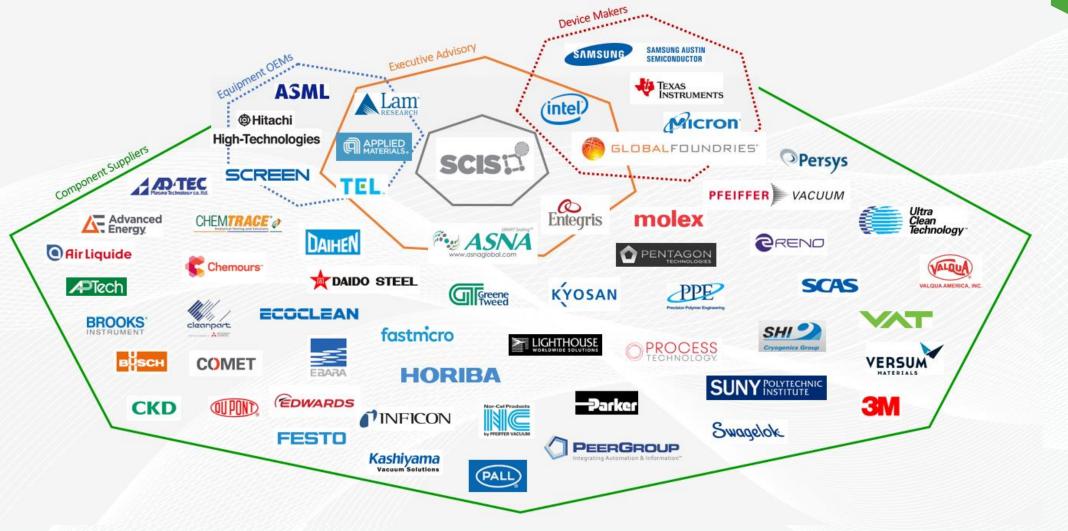
(Semiconductor Components, Instruments, and Subsystems)

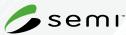
- <u>Focus</u>: Establishing a baseline for measuring defects introduced by process-critical components.
  - Particle or defect limits will not be defined but will focus on defining consistent methodologies for measuring defects.

- SCIS provides a forum that fosters discussion and aligns stakeholders on pre-competitive industry-critical issues.
  - Participants are not expected to disclose IP but are expected to provide parameters for standardized measurement.

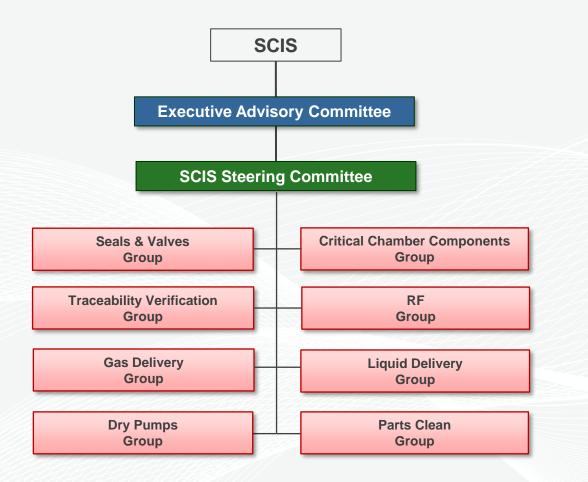


# **Participating Companies**



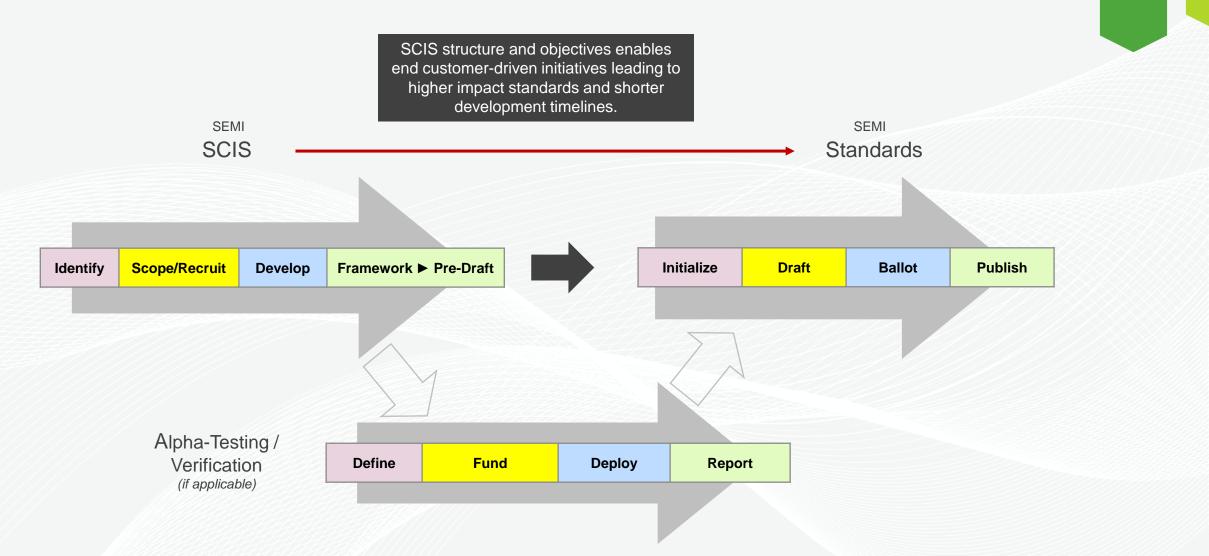


# SCIS Organizational Structure



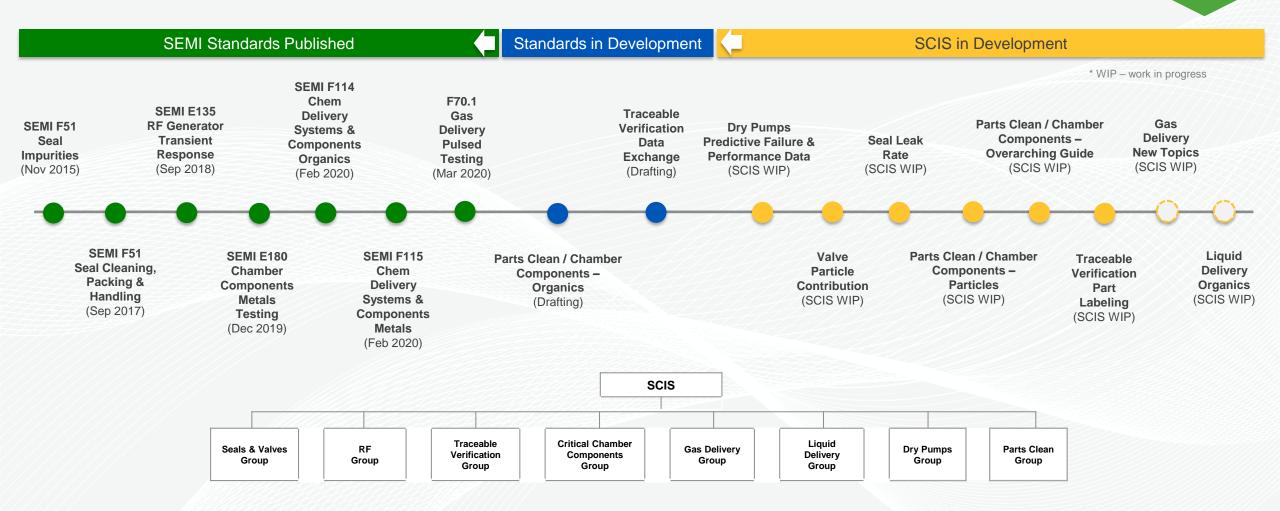


#### SCIS to Standards – Process Flow





## SCIS Standardization Initiatives – Status







# Semiconductor Components, Instruments and Subsystems (SCIS)

Technology Community

Joint Parts Clean and Critical Chamber Components (CCC) WGs







- Current Activities:
  - Organics
  - Particles
  - "Over-arching" document on parts cleaning



- The WG has been focusing on:
  - "Over-arching" document on parts cleaning [1/2]
    - WG lead: Victor Chia (Air Liquide/Balazs)
    - WG plans to develop over-arching document into a full consensus Standard as a Guide
    - The Guide will provide users information on available test methods. It will be up to the user to determine which technique will be used for their needs
    - The Guide can also be referenced by users/customers
    - Next Meeting: Wednesday, December 7 at 8 AM (Pacific)

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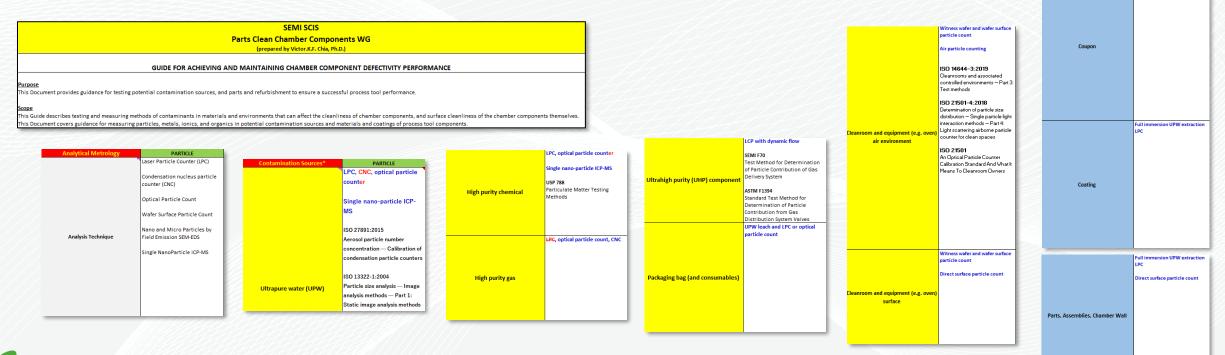
- The WG has been focusing on:
  - Particles [1/3]
    - WG Leads: Tommaso Orzali (ASML), Fuhe Li (Balazs), Erik Vermeulen (Fastmicro)
    - 3 parallel activities:
      - Guide Document + Test Method (Tape Lift-off) + Test Method (OPC/LPC)



- The WG has been focusing on:
  - Particles [2/3]

#### **Guide Document**

Guide Document would be incorporated into the Over-arching Document effort



- The WG has been focusing on:
  - Particles [3/3]

#### Test Method for Tape Lift-off

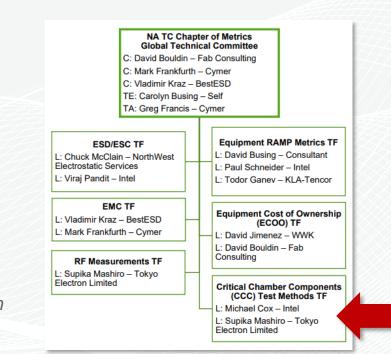
- Describes a quantitative analysis method for measuring ISO 14644-9 Surface Cleanliness by Particle concentration (SCP) of critical chamber components by using a replacement adhesive substrate to remove particles from the surface of interest and to measure them with a scatterometer or scanning surface inspection system (for particle counting) and then further analysis (via SEM/EDX) to identify elemental composition of particles
- WG will continue to align on key elements/framework under this SCIS WG
- This activity will eventually be moved to SEMI Standards for formal standards development

#### Test Method for OPC/LPC/Flushing

- Drafting, to be discussed at next meeting
- <u>Next meeting</u>: Wednesday, December 7 at 8 AM (Pacific)



- The WG has been focusing on:
  - Organics
    - In progress draft circulated among WG members for inputs
      - Approach to structure is similar to SEMI E180, focusing on critical chamber components (CCC)
    - This activity has been transitioned to SEMI Standards for formal development
      - (SNARF # 6931) New Standard: Test Method for Measuring Organics Contamination through Thermal Desorption or Solvent Extraction Gas Chromatography Mass Spectrometry of Critical Chamber Components Used in Semiconductor Wafer Processing and Inspection





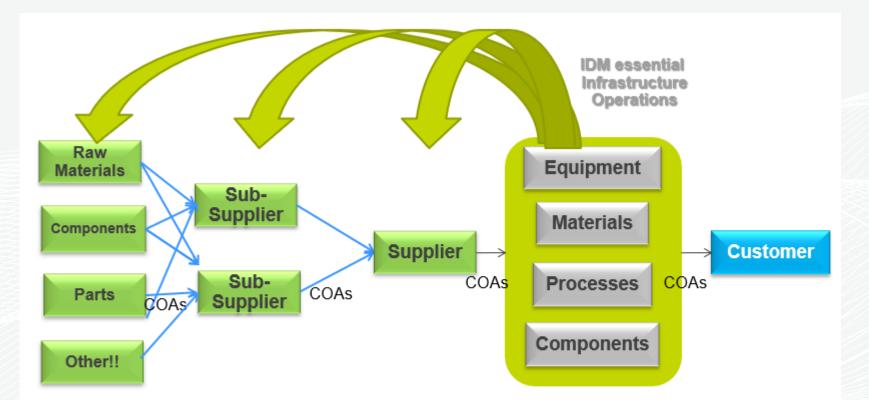
### Semiconductor Components, Instruments and Subsystems (SCIS)

Technology Community

**Traceable Verification** 



## Traceable Verification - Requires Data Integration



Collaboration, Traceability & Standards are key Ingredient to ensure alignment

In Line process monitoring controls and traceability at every stage goes far beyond the outgoing COAs of supply chain



### Requirements

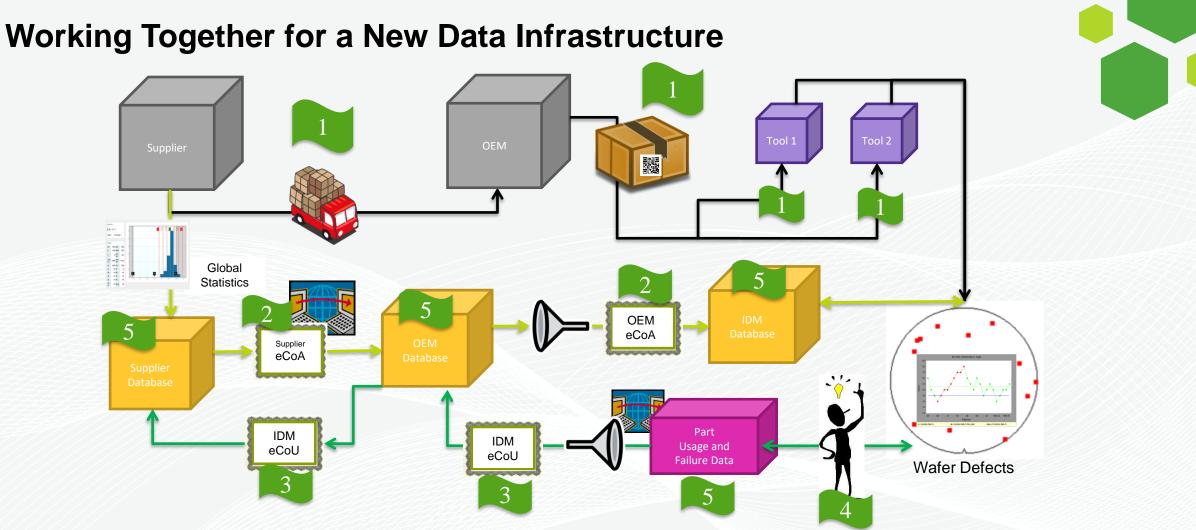


- Standardized Identification (SNARF# 6448)
- Easy ID e.g. 2D Bar code will link to UUID for data reference
- Standardized Data Format (SNARF# 6449)
  - Standardized scalable Information Exchange templates by commodity
    - ECOC/ECOA templates
- 3
- Data Push method extensions to Standardized Data Format
- Deliver information prior to receipt and point of use
- COU Certificate of Use back to supplier (Failure modes, lifetime and CIP, etc.)
- 4

#### Data Pull method

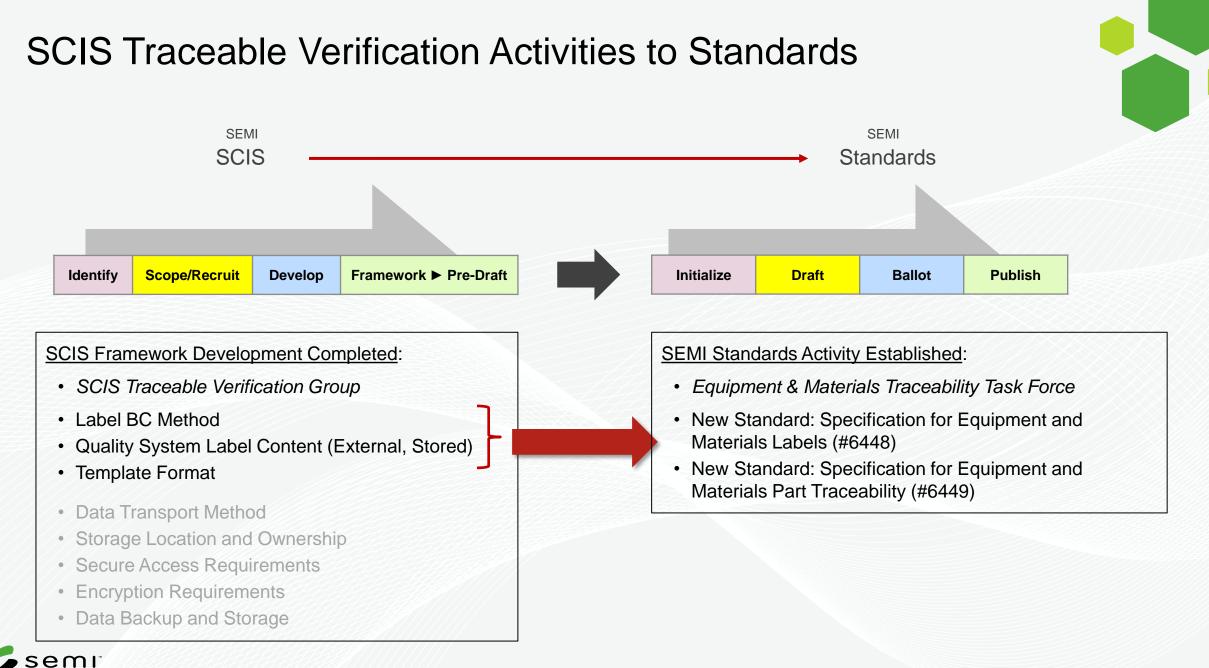
- Supplier / Source Web Site
- 5 History Tracking System (Use and Failure)
  - External (supplier)
  - Internal (customer)





- Sharing manufacturing data on parts and materials is critical for improvement and excursion containment
- Fabs must use data to find and share learnings with suppliers and IDMs
- Easy look up of "missing" data





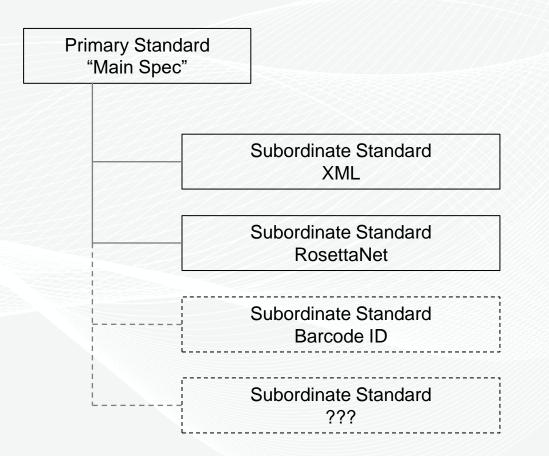
#### Equipment & Materials Traceability Task Force Activities & Status [1/2]

- New Standard: Specification for Equipment and Materials Labels (SEMI Draft Document # 6448)
  - Ballot was developed using VDA 4992 MAT Label and eMat data exchange at the Material Label format.
  - SEMI has held separate meetings with OEM and IDM representatives to discuss concerns as well as efforts to realize material traceability.
  - Status:
    - Current 6448 SNARF will be abolished
      - This will take place at the North America Chapter of the Traceability Technical Committee meeting on November 10
    - The TF plans to start a new activity based on an alternative standardization approach
      - Discussions on the new standardization approach will be taken back to SCIS Traceable Verification WG for re-engineering (this removes 6448 from the balloting process for now)
      - Next SCIS Traceable Verification WG meeting to be announced
    - The TF also plans to continue its other existing activity in parallel (6449 eCOA)
      - A strawman document will be circulated once drafting is complete
    - OEM stakeholders are requested to engage at the document development level



#### Equipment & Materials Traceability Task Force Activities & Status [2/2]

- New Standard: Specification for Equipment and Materials Part Traceability (SEMI Draft Document# 6449)
  - Purpose: Specification for communicating part quality
    - Standardized scalable electronic Information Exchange templates by commodity eCOC/ECOA Templates
  - Status: Drafting in progress
  - Looking for samples of suppliers' eCOA to ensure all information is captured in the new Standard
  - Ballot contributors always welcome!





#### Semiconductor Components, Instruments and Subsystems (SCIS)

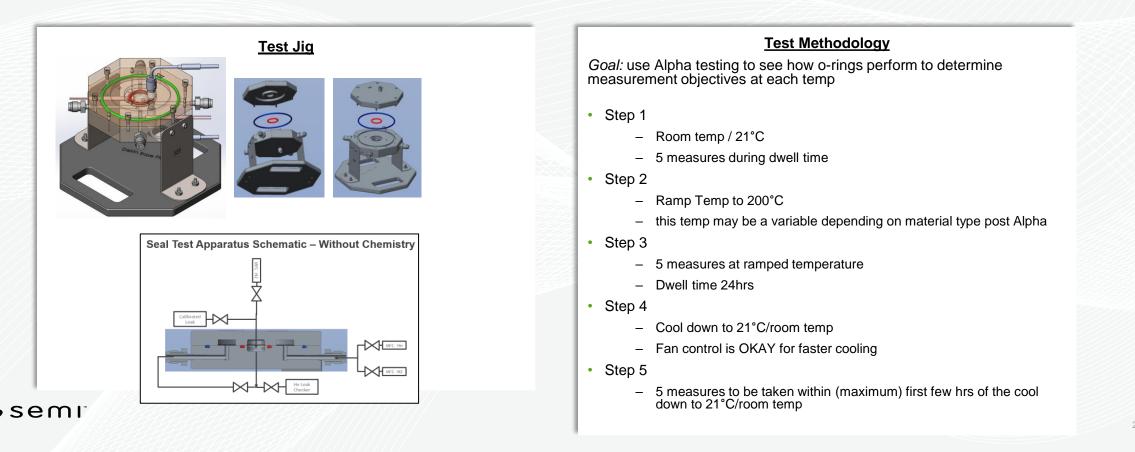
Technology Community

Seals WG



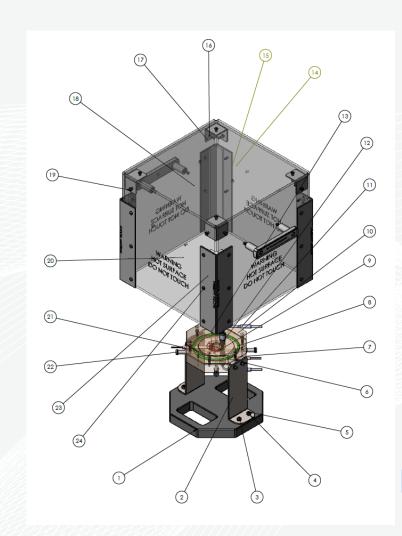
#### SCIS Seals Group Leak Rate Project [1/4]

- Focus: Seal Leak Rate
  - <u>Rationale</u>: Seal failure can generate defects through atmospheric leaks into process environments or from degraded seal material. There is a need to develop a standardized way for measuring a seal's ability to hold vacuum when exposed to elevated temperatures and/or process and clean chemistries.



#### SCIS Seals Group Leak Rate Project [2/4]

• BOM



		REVISIONS											
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	8		-242 Oring						00AP			1	
	9	-214 Oring	3						UT			1	
	10	Top Plate				Machine Part: 316 Stainless Steel						1	
	11	TC with Bayonet Fitting			ng	BT-090-K-2 1/4-60-2					2		
	12	Adapter E .4380D x	Adapter Bayonet .4380D x .2811D			BTA-2					2		
	13	McMaster	7395A	441	Dowel Pin, 316 Stainless Steel, 1/8" Diameter, 1/2" Long					3			
	14	McMaster	McMaster #: 10995A19 McMaster #: 92196A801			High-Temperature Plastic Pull Handle with Unthreaded Through Holes, 4- 1/4" Wide Center-to-Center					2		
	15	McMaster				18-8 Stainless Steel Socket Head Screw, 1/4"-20 Thread Size, 2" Long, Fully Threaded						4	
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#### SCIS Seals Group Leak Rate Project [3/4]

- Operating Procedures
  - Provides detailed, step-by-step procedures for conducting seal leak rate alpha test
- Alignment needed on key requirements
  - O-ring prep prior to testing
  - Room temperature range
  - # of leak rate measurements taken
  - Ramp temperature, gradient
  - Dwell time
  - Conditioning



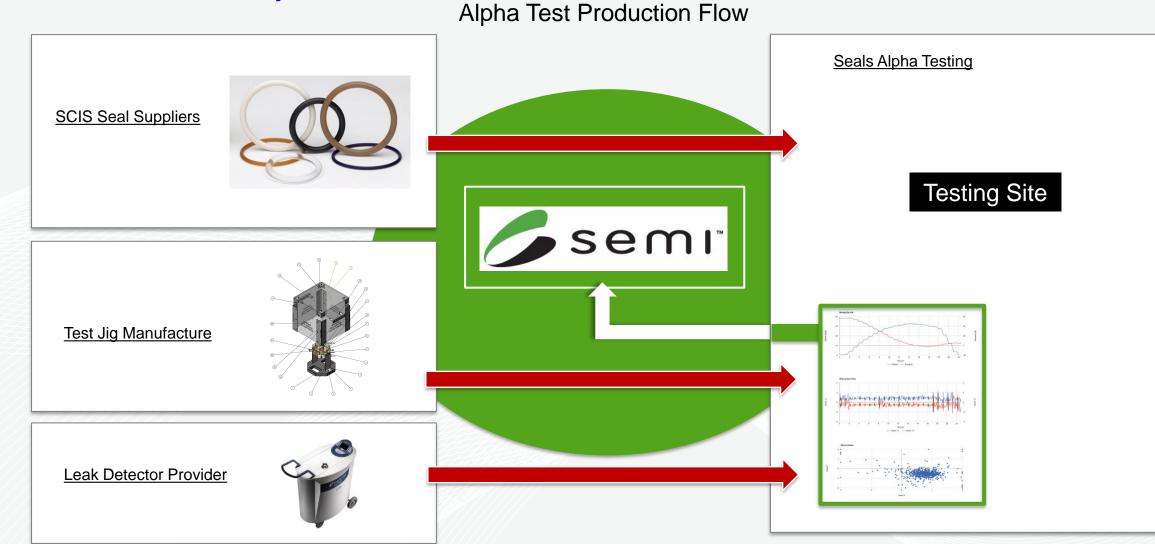
#### **Operating Procedures – Contents:**

- 1) Safety
- 2) Background Information
- 3) O-Ring Test Jig Facilities & Hardware Requirements
- 4) Configuring the O-Ring Test Jig for Operation
- 5) Calibrating the O-Ring Test Jig for Operation
- 6) Preparing an O-Ring for Leak-Rate Test on the Jig
- 7) Running an O-Ring Leak-Rate Test on the Jig
- 8) Recording an O-Ring Leak-Rate Test Result
- 9) Calculating Gauge Repeatability & Reliability
- 10) Alpha Testing Sampling Requirements





#### SCIS Seals Group Leak Rate Project [4/4]





#### SCIS Seals Group Project Contributions - Update

Item / Resource	Contributor	Status
Testing Site	TELUS	Confirmed
Leak Detector	Edwards	Confirmed
Valves	CKD USA	Confirmed
Fittings	Swagelok	Confirmed
PLC	Festo	Confirmed
Test Fixture - Assembly	TEL US	Confirmed
Test Fixture - Materials	TEL US	Fixture (machined) parts done – early Nov 2022
Firestop Material / Thermal Insulation	???	Discussion in progress Ongoing discussion re: material details

Many thanks to our contributors!!



#### Semiconductor Components, Instruments and Subsystems (SCIS)

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**Dry Pumps** 



# Dry Pumps

- Background:
  - Critical pump data can be utilized for predictive pump failure detection. Some of this data can be obtained today while others are not yet widely available.
  - Parameters evaluated include:

    - Temperature
    - Speed

semi

- Inlet PressureVibration NoiseExhaust PressurePump Run Hours

  - Power, Current
    - N2 Purge
- Reviewed existing standards
  - ISO (vibration on rotational equipment)
  - SEMI (data communication, specific device model)
    - SEMI E73, Specification for Vacuum Pump Interfaces Dry Pumps
    - SEMI E54.18, Specification for Sensor/Actuator Network Specific Device Model for Vacuum Pump Device

#### Pump Data Survey (excerpt)

Parameter	(a) Is this data available today?									
	Input #1	Input #2	Input #3	Input #4	Input #5	Input #6	Input #7	Cumulative		
Inlet Pressure	N	Y (as fab)	N	N	N	N	Y	~N		
Vibration	N	N	N	N	N	N	Y	N		
Noise	N	N	N	N	N	N	Y	~N		
Temperature				Y						
<ul> <li>Cooling Water Flow, Temperature</li> </ul>	Y	Y	Y & N	N	Y	Y	Y	~Y		
<ul> <li>Lack of Cooling Water</li> </ul>	Y	Y	Y	N	Y	N	Y	~Y		
Speed	Y/N	Y	Y	Y	Y	Y	Y	~Y		
Exhaust Pressure	Y	Y	Y	Y	Y	Y	Y	~Y		
Pump Run Hours	Y/N	Y	Y	Y	Y	Y	Y	~Y		
Power, Current	Y	Y	Y	Y	Y	Y	Y	Y		
N2 Purge*	Y	Y	Y	Y	Y	Y	Y	Y		



# Dry Pumps



- Status: Drafting completed on guide for measuring vibration
- Guide for Measuring Vibration of Dry Pumps
  - There are many pump parameters that can be used to determine its health → Vibration is just one of these parameters
  - Draft provides guidance on how vibration measurements are taken for dry pumps
  - Draft also provides guidelines for evaluating pumps for use at customer sites
  - Elements considered include:
    - Sensor Considerations
      - Type
      - Location
      - # of Sensors

- Data Collection
  - Interface

Sampling Rate

• Frequency

- Communication
- This guide does not address how the data is processed to determine the health of the pump



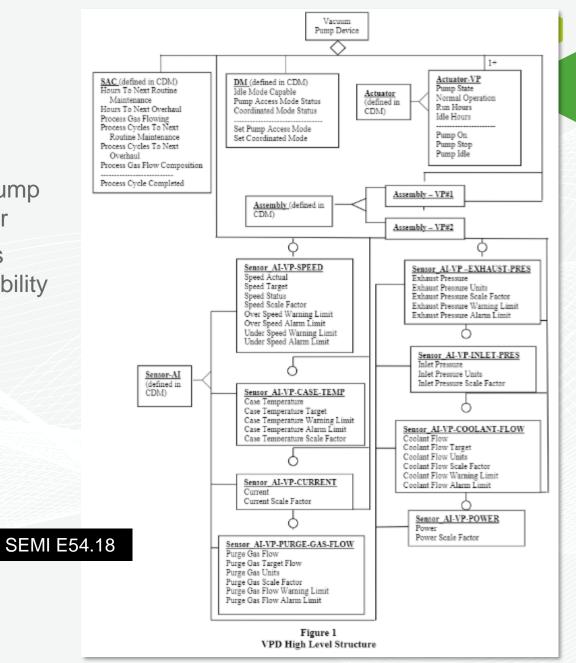
# **Inputs Received**

- WG Discussion
  - Input received calls for 2 parts (signal, alarm)
  - Most customers want the signal and they do their own processing
  - WG to take a closer look at SEMI E54.18 and SEMI E54.1 standards
    - SEMI E54.18 Specification for Sensor/Actuator Network Specific Device Model for Vacuum Pump Device
    - SEMI E54.1 Standard for Sensor/Actuator Network Common Device Model
    - Revision to incorporate vibration signal
  - Current vibration draft:
    - Refers to E54.18 (or other accepted methods) for communicating vibration signal
    - Acknowledges data processing, but does not address it (outside of scope, IP sensitivity)



# Dry Pumps - Status

- Next Steps
  - WG soliciting inputs on whether to take on pump communication or move on to next parameter
  - If on pump communication, should the efforts focus on new tools vs on backwards compatibility for old tools?





### Semiconductor Components, Instruments and Subsystems (SCIS)

Technology Community

Valves WG



# **SCIS** Valves Activity



- Particle Contribution from Slit Valves (Wafer Transfer Valves)
  - <u>Rationale</u>: There is interest in minimizing particles generated by either elastomer or valve assembly
    - Traditionally, at qualification the particle contribution of valves & original elastomer are considered
    - Usually, the next step is the introduction of CIP elastomer
    - If CIP elastomer proves superior (i.e., less particle shed) than original elastomer, then focus can shift to optimizing valve operation parameters (if performance improvement of elastomer is deemed insufficient)
    - And/or if CIP elastomer still fails to meet performance criteria, then focus shifts to changing valve design, valve operation

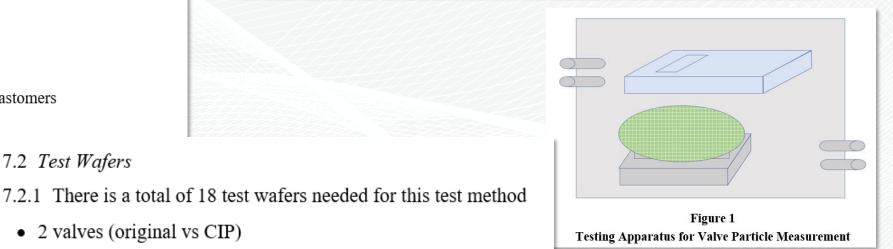


- Particle Contribution from Slit Valves (Wafer Transfer Valves)
  - Status: Drafting in Progress
  - 9.1.2.2 Material properties to be provided by elastomer supplier
    - Hardness
  - Tensile modulus and strength
  - Elongation
  - · Coefficient of thermal expansion
  - · Compression set
  - Operating temperature range
  - Tr10 or Tg for low temperature elastomers
  - Plasma resistance (wt.% loss)
  - Filler material
  - · He permeation
  - Outgassing

semi

12.2 Baseline Measurements from Released Valve & Elastomer

- 12.2.1 The valve is tested against three different cycle conditions:
- ~2000 cycles to immediately assess CIP elastomer performance
- ~25,000 cycles to account for non-linear behavior of seal under test
- ~50,000 cycles for a lifetime evaluation test



- 3 tests (quick test vs lifetime vs intermediate)
- 3 measurements for each set up

2 valves (original vs CIP)

7.2 Test Wafers

40

- Particle Contribution from Slit Valves (Wafer Transfer Valves)
  - <u>Status</u>: Drafting in Progress

#### 7.2 Test Wafers

- 7.2.1 There is a total of 18 test wafers needed for this test method
  - 2 valves (original vs CIP)
  - 3 tests (quick test vs lifetime vs intermediate)
  - 3 measurements for each set up
- 7.3 Measurement Equipment
- 7.3.1 Wafer Inspection Tool with SP5 Capability

Current draft calls for wafer inspection tool with SP5 capability.

There are concerns regarding accessibility of such equipment.

Are there other alternative measurement approaches that still meet current (and emerging) process needs?







- Previous outreach efforts to other valve manufacturers (SMC, V-Tex, GNB Group), unfortunately, did not lead to new participation
- Valves WG is in search for stakeholders willing to drive working particles draft to completion
- In the mean time, the WG continues to solicit feedback on the working draft



# New SCIS Activity Proposed for 2023

- Subfab Data Integration
  - It would help Fabs to address a scaling challenge when seeking to contextualize the data. The general intent would be to address known missing FMEA signals (for vacuum health and other key parameters). Therefore, there is a desire for either a new standard or clearer guidelines.
- Suggested Next Steps
  - Sub-fab is a broad topic, encompasses multiple components. There are also environmental/regulatory considerations
  - Before forming any dedicated WGs (e.g., on abatement, on chillers), an SCIS community-wide survey will be issued to specifically identify key subfab areas of concern, pain points, etc.
    - Survey would be issued YE2022 or early 2023



## SCIS Meeting Calendar 2023 (Proposed)

#### **SCIS F2F Meetings**

April 3 10:00 AM to 2:00 PM, Pacific

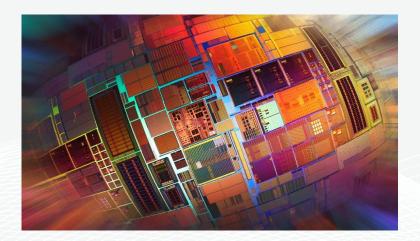
July 12 @ SEMICON West 2023 12:00 Noon to 2:00 PM, Pacific

Late-Oct, early-Nov 2023 10:00 AM to 2:00 PM, Pacific

- SEMI Industry Strategy Symposium (ISS) (January 8-11) in Half Moon Bay, CA
- NA Standards Spring 2023 Meetings (April 3-6) in Milpitas, CA
- SEMI Advanced Semiconductor Manufacturing Conference (ASMC) (May 1-4) in Saratoga Springs, NY
- SEMICON West 2023 (July 11-13) in San Francisco, CA



# **Contact Information**



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### **Published SCIS Standards**

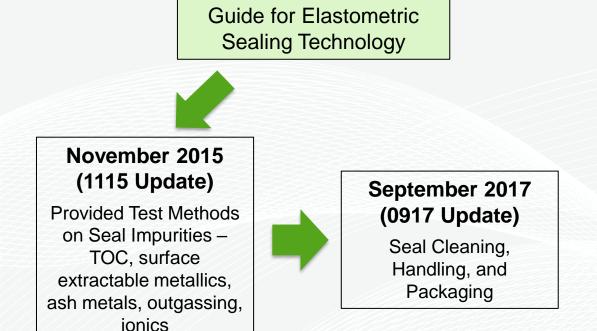
**SEMI F51** 

### **SEMI E135**

Test Method for RF Generators to Determine Transient Response for RF Power Delivery Systems Used in Semiconductor Processing Equipment

#### September 2018 (0918 Update)

- Define nominal load, high impedance load and low impedance load
- Add new Related Information section covering:
  - Rationale for the limited number of required test loads
  - Expected control system gain variation as a function of load impedance on a linear load
  - Nonlinear (plasma) loads





### **Published SCIS Standards**

#### **SEMI E180**

Test Method for Measuring Surface Metal Contamination Through ICP-MS of Critical Chamber Components Used in Semiconductor Wafer Processing

#### **New Standard**

 Provides a method for a quantitative analysis for surface trace-metal concentration of critical chamber components (CCCs) by using inductively coupled plasma-mass spectrometry (ICP-MS)



### **Published SCIS Standards**

SEMI F70.1 - Test Method for Determination of Particle Contribution of Gas Delivery System

- Provides a standardized methodology and procedure for measuring the particle contribution performance of a gas delivery system in terms of number of particles added to gas flowing through the system.
- Applies to surface mount and conventional gas delivery systems used in semiconductor manufacturing equipment.

**SEMI F114** - Test Method for the Determination of Organic Contaminants Present on Wetted Surfaces of Ultra High Purity Chemical Delivery Systems and Components

- Defines a test method for determining organic compounds on the wetted surfaces of ultra high purity (UHP) chemical delivery systems and components.
- Examples of test samples include valves, regulators, filters, and mass flow controllers, tubing, weld fittings, and face seal fittings.

**SEMI F115** - Test Method for the Determination of Metallic Elements Present on Wetted Surfaces of Ultra High Purity Chemical Delivery Systems and Components

 Defines a test method for determining metallic elements present on the wetted surfaces of ultra high purity (UHP) chemical delivery systems and components.



- Seal Leak Rate
  - <u>Rationale</u>: Seal failure can generate defects through atmospheric leaks into process environments or from degraded seal material. There
    is a need to develop a standardized way for measuring a seal's ability to hold vacuum when exposed to elevated temperatures and/or
    process and clean chemistries.

#### • Particle Contribution from Slit Valves (Wafer Transfer Valves)

- <u>Rationale</u>: There is interest in minimizing particles generated by either elastomer or valve assembly
  - Traditionally, at qualification the particle contribution of valves & original elastomer are considered
  - · Usually, the next step is the introduction of CIP elastomer
  - If CIP elastomer proves superior (i.e., less particle shed) than original elastomer, then focus can shift to optimizing valve operation parameters (if performance improvement of elastomer is deemed insufficient)
  - And/or if CIP elastomer still fails to meet performance criteria, then focus shifts to changing valve design, valve operation
- Pump Data for Predictive Pump Failure Detection
  - <u>Rationale</u>: Critical pump data can be utilized for predictive pump failure detection. Some of this data can be obtained today while others are not yet widely available.
- Organic Contamination from Critical Components in Relevant Solvents
  - <u>Rationale</u>: Evidence from end-users has linked organic contamination to wafer quality. To date, no standards exist for determining relative organic levels from critical components most preferably on a bulk and specific basis.
- **RF Generator Reliability** SCIS is revisiting topic and plans to identify key contributing issues



### Parts Cleaning

- <u>Rationale</u>: Defectivity can be introduced by various sources during parts cleaning process. There is a need for guidance on available test methodologies and other considerations that impact part cleanliness.
  - Activities on organics, particles as well as development of an over-arching guide for achieving and maintaining chamber component defectivity performance



### Dry Pumps Survey Results [1/2]

• Compiled (a)

Parameter	(a) Is this data available today?								
	Input #1	Input #2	Input #3	Input #4	Input #5	Input #6	Input #7	Cumulative	
Inlet Pressure	N	Y (as fab)	Ν	N	Ν	N	Y	~N	
Vibration	N	N	Ν	N	Ν	N	Y	N	
Noise	N	N	Ν	N	N	N	Y	~N	
Temperature				Y					
<ul> <li>Cooling Water Flow, Temperature</li> </ul>	Y	Y	Y & N	N	Y	Y	Y	~Y	
<ul> <li>Lack of Cooling Water</li> </ul>	Y	Y	Y	N	Y	N	Y	~Y	
Speed	Y/N	Y	Y	Y	Y	Y	Y	~Y	
Exhaust Pressure	Y	Y	Y	Y	Y	Y	Y	~Y	
Pump Run Hours	Y/N	Y	Y	Y	Y	Y	Y	~Y	
Power, Current	Y	Y	Y	Y	Y	Y	Y	Y	
N2 Purge*	Y	Y	Y	Y	Y	Y	Y	Y	



### Dry Pumps Survey Results [2/2]

• Compiled (b)

Parameter	(b) Is this data useful?							
	Input #1	Input #2	Input #3	Input #4	Input #5	Input #6	Input #7	Cumulative
Inlet Pressure	Y	Y	N/Maybe	Y	Y	Y	Y	~Y
Vibration	Y	Y/N	N/Maybe	nice to have	Y	Y	Y	~Y
Noise	N	Y	N/Maybe	nice to have	Y	Y	Y	~Y
Temperature				Y				
<ul> <li>Cooling Water Flow, Temperature</li> </ul>	Y	Y	Y	Y	Ν	Y	Y	~Y
<ul> <li>Lack of Cooling Water</li> </ul>	Y	Y	Y	Y	Y	Y	Y	Y
Speed	Y/N	Y	Y	Y	Y	Y	Y	~Y
Exhaust Pressure	Y	Y	Y	Y	Y	Y	Y	Y
Pump Run Hours	Y/N	Y	Y	Y	Y	Y	Y	~Y
Power, Current	Y	Y	Y	Y	Y	Y	Y	Y
N2 Purge*	Y	Y	Y	Y	Y	Y	Y	Y

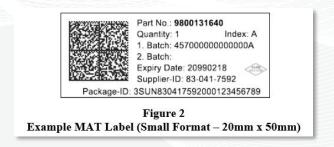


### Equipment & Materials Traceability Task Force Activities & Status [1/5]

- New Standard: Specification for Equipment and Materials Labels (SEMI Draft Document # 6448)
  - To define material Bar Code Label (BCL) standard for all incoming direct materials, parts, and consumables for semiconductor manufacturing.
  - Addresses traceability requirements along the incoming material and parts supply chain to enable effective isolation of defects in the manufacturing process or post manufacturing quality investigation
  - For suppliers and Original Equipment Manufacturers (OEMs) of direct materials, parts, consumables, repaired parts, clean parts and refurbish parts that have a Certificate of Analysis (COA) or Certificate of Conformance (CoC)
  - Specifies data that is included in Equipment and Material Labels for both machine readable 2D barcode and human readable format in accordance with VDA 4992 - MAT Label and eMat data exchange

	Part.No.: Quantity:	9800131640 1	Index: A MS-Level: 1
	,	: AV452127CF	NR2
	Part Name:	Anvil (2000 K	G)
PERSONAL PROPERTY AND	Package-ID:	3SUN830417	592000123456789
1. Batch: 45700000	A0000000A	Prod. Date:	20200424
2. Batch:		Expiry Date:	20990218
Supplier-ID: 83	-041-7592	Supplier:	NumberOne Corporation
Order Number: AB	CXYZ	Delivery Note	
Man. Part-No: SL	105103MAA-S		
Man. Location: US	-Anaheim		Rolds
Supplier-Data:			an a ber

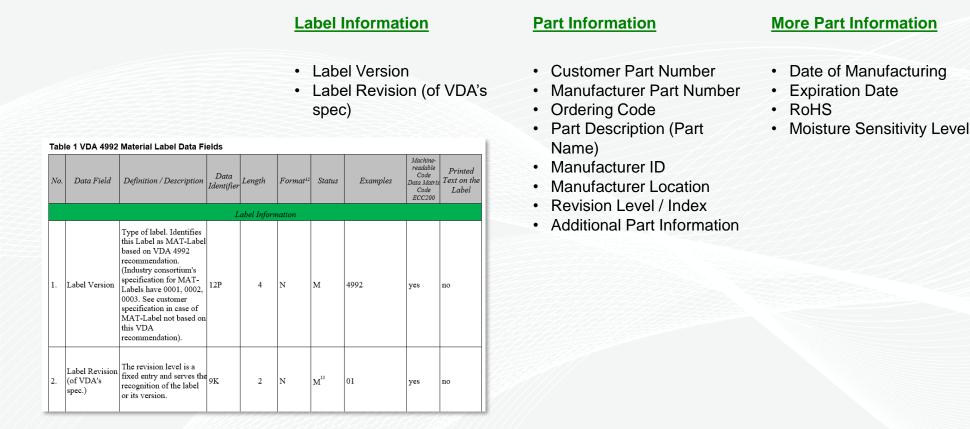
Figure 1 Example MAT Label (Large Format – 45mm x 78mm)





### Equipment & Materials Traceability Task Force Activities & Status [2/5]

• New Standard: Specification for Equipment and Materials Labels (SEMI Draft Document # 6448)



#### Logistic and Traceability Information

- Supplier Name
- Supplier ID (or DUNS number)
- Package ID
- Quantity
- Unit of Measure
- Batch-No (e.g., volume, production)
- Batch-No (for clean or repair)
- Order Number
- Delivery Note Number
- Supplier Data

### Equipment & Materials Traceability Task Force Activities & Status [3/5]

- New Standard: Specification for Equipment and Materials Labels (SEMI Draft Document # 6448)
  - Material Label Use Case Scenarios (as part of Related Information Section)

VDA 4992 Field Number	VDA 4992 Data Field	Mapping
4	Manufacturer Part Number	<ul> <li>Part Number.</li> <li>A cleaned or repaired part number can be different than the original OEM part number.</li> <li>A supplier may choose to use a different part number to indicate it is refurbished.</li> </ul>
5	Ordering Code	Secondary Part information such as drawing number, software revision on controller etc. It could also include a cleaning supplier's assigned part number, which may referenc part and/or cleaning procedure.
10	Additional Part Information	Information agreed to between Customer and Supplier. (e.g., number of times the part was cleaned).
11	Date of Manufacturing	Date of cleaning or refurbishment
20	Batch-No. #1	<ul> <li>Information about the original material or part.</li> <li>If the cleaned or repaired part number is different than the original part number, this field contains the original part number as the first piece of information in th data field.</li> </ul>
21	Batch-No. #2	Information about the cleaning process (e.g., cleaning batch information).
22	Order Number	Customer PO Number.

#### **Cleaned Part**

#### Table R1-2 Cleaned or Refurbished Part Use Case Data Field Mappings

#### New Part

VDA 4992 Field Number	VDA 4992 Data Field	Mapping
5	Ordering Code	Secondary Part information such as drawing number, software revision on controllers, etc.
		<ul> <li>The GTIN or EAN manufacturer part number is recorded in this field.</li> </ul>
20	Batch-No. #1	Information about the material or part.
21	Batch-No. #2	Hardcoded value as an empty string ("").
22	Order Number	Customer PO Number.

#### **Consumable Material**

#### Table R1-3 Photo Resist Use Case Data Field Mappings

VDA 4992 Field Number	VDA 4992 Data Field	Mapping
5	Ordering Code	<ul> <li>Secondary Part information such as drawing number, software revision on controllers, etc.</li> <li>The GTIN or EAN manufacturer part number is recorded in this field.</li> </ul>
20	Batch-No. #1	Information about the material.
21	Batch-No. #2	Hardcoded value as an empty string ("").
22	Order Number	Customer PO Number.



# **Contact Information**



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